Si Time [®]	Title:	Performance Report SiT8008B, 100MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

This report contains sample performance data for SiT8008B-100MHz.

Conditions:

- Frequency 100 MHz
- Vdd 1.8V, 2.5V, 2.8V, 3.0V, 3.3V
- Temperature 25℃
- Termination:
 - No load for IDD
 - $\circ~~50\Omega$ to GND for phase noise
 - $\circ \quad 15 pF \text{ for other tests} \quad$

Equipment:

- Agilent DSA90604 oscilloscope (6GHz, 20Gsps)
 - o Period jitter, waveform, rise/fall time, duty cycle, amplitude
- Agilent E5052B Signal Source Analyzer
 - Phase noise, integrated phase jitter
- Power supply current
 - Agilent 34401A DMM

Data:

- Random Phase jitter, Period Jitter, Duty cycle, Rise/Fall time, Amplitude, Idd
- Output waveforms
- Frequency stability versus temperature

Parameter	Units	Voltage				
	Onits	1.8 V	2.5 V	2.8 V	3.0 V	3.3 V
Random Phase jitter (900kHz - 20MHz)	ps, rms	0.56	0.67	0.68	0.69	0.69
Random Phase jitter (12kHz - 20MHz)	ps, rms	1.30	1.45	1.48	1.48	1.48
Period jitter	ps, rms	1.84	1.63	1.62	1.61	1.61
Period jitter (10,000 cycles)	ps, pk-pk	13.1	11.8	11.4	11.3	11.6
Duty cycle	%	49.6	49.5	50.3	51.0	51.5
Rise time (20% - 80%)	ns	1.26	1.04	0.96	1.01	0.96
Fall time (80% - 20%)	ns	1.26	1.00	0.92	0.99	0.94
Amplitude	V	1.78	2.49	2.79	3.02	3.32
Current consumption (no load, output enabled)	mA	4.63	5.04	5.23	5.32	5.52
Current consumption (no load, output disabled)	mA	3.57	3.65	3.70	3.74	3.81

Table 1. Performance data

Si Time [®]	Title:	Performance Report SiT8008B, 100MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014



Figure 1. Duty cycle, Rise/Fall time and Amplitude 1.8V

The information contained in this document is confidential and proprietary to SiTime Corporation. Unauthorized reproduction or distribution is prohibited.

Page 2 of 11

	Title:	Performance Report SiT8008B, 100MHz		
Si Time ^{**}	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

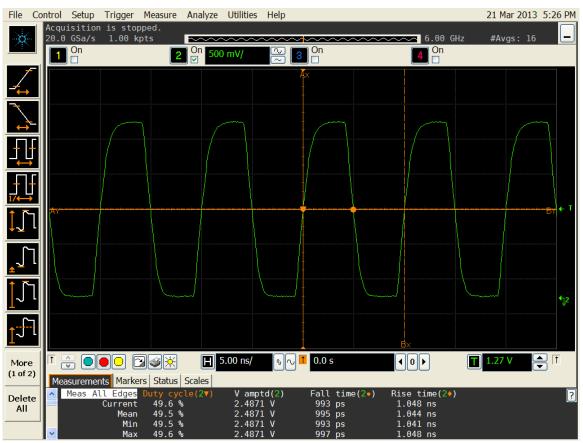


Figure 2. Duty cycle, Rise/Fall time and Amplitude 2.5V

The information contained in this document is confidential and proprietary to SiTime Corporation. Unauthorized reproduction or distribution is prohibited.

Page 3 of 11

Si Time [®]	Title:	Performance Report SiT8008B, 100MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

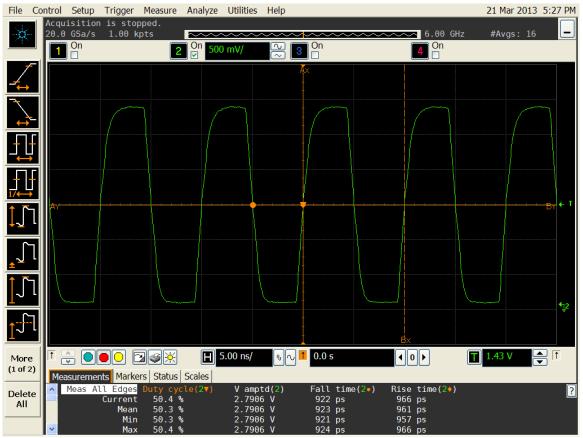


Figure 3. Duty cycle, Rise/Fall time and Amplitude 2.8V

Si Time ^{**}	Title:	Performance Report SiT8008B, 100MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014



Figure 4. Duty cycle, Rise/Fall time and Amplitude 3.0V

Si Time ^{**}	Title:	Performance Report SiT8008B, 100MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014



Figure 5. Duty cycle, Rise/Fall time and Amplitude 3.3V

	Title:	Performance Report SiT8008B, 100MHz		
Si Time [®]	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

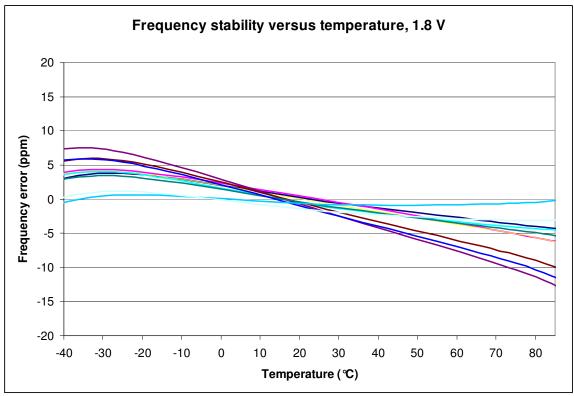


Figure 6. Frequency stability* versus temperature, 1.8 V

*Please note that frequency stability in SiTime devices is not depended on output frequency.

	Title:	Performance Report SiT8008B, 100MHz		
Si Time [®]	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

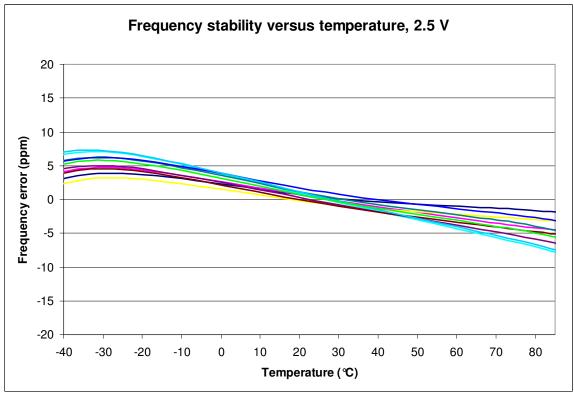


Figure 7. Frequency stability versus temperature, 2.5 V

Page 8 of 11

	Title:	Performance Report SiT8008B, 100MHz		
Si Time [®]	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

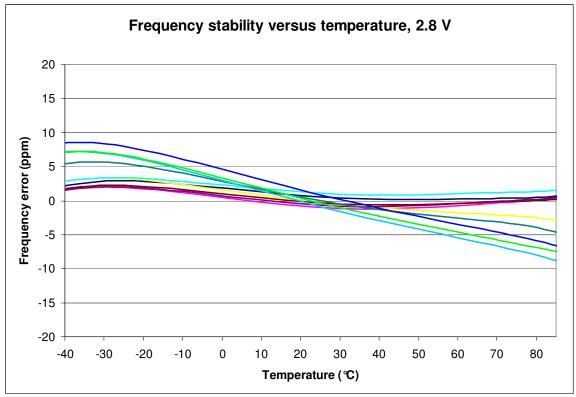


Figure 8. Frequency stability versus temperature, 2.8 V

	Title:	Performance Report SiT8008B, 100MHz		
Si Time [®]	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

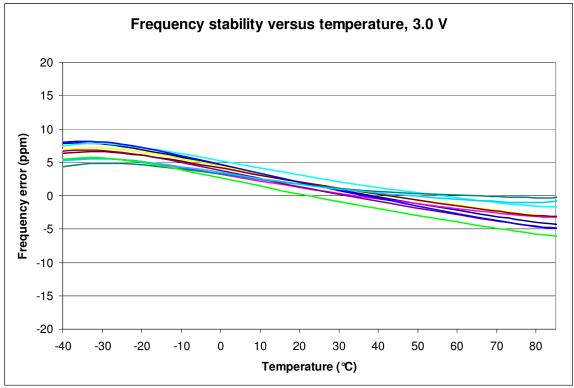


Figure 9. Frequency stability versus temperature, 3.0 V

Page 10 of 11

	Title:	Performance Report SiT8008B, 100MHz		
Si Time [®]	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

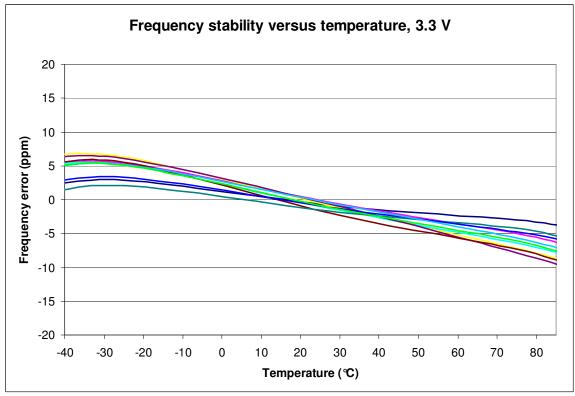


Figure 10. Frequency stability versus temperature, 3.3 V

The information contained in this document is confidential and proprietary to SiTime Corporation. Unauthorized reproduction or distribution is prohibited.